

Operational Amplifiers

LM158/LM258/LM358 dual op amps

general description

The LM158 series consists of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, dc gain blocks and all the conventional op amp circuits which now can be more easily implemented in single power supply systems. For example, the LM158 series can be directly operated off of the standard ± 5 V_{DC} power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional ± 15 V_{DC} power supplies.

unique characteristics

- In the linear mode the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.
- The unity gain cross frequency is temperature compensated.
- The input bias current is also temperature compensated.

advantages

- Eliminates need for dual supplies
- Two internally compensated op amps in a single package

- Allows directly sensing near GND and V_{OUT} also noes to GND
- Compatible with all forms of logic
- Power drain suitable for battery operation
- Pin-out same as LM1558/LM1458 dual operational amplifier

features

- Internally frequency compensated for unity gain
- Large dc voltage gain

100 dB 1 MHz

- Wide bandwidth (unity gain)
 - (temperature compensated) Wide power supply range:

Single supply or dual supplies

3 V_{DC} to 30 V_{DC} $\pm 1.5 V_{DC}$ to $\pm 15 V_{DC}$

- Very low supply current drain ($500\mu A$) essentially independent of supply voltage (1 mW/op amp at +5 V_{DC})
- Low input biasing current (temperature compensated)

45 nA_{DC}

temperature compensated

2 mV_{DC}

 Low input offset voltage and offset current

5 nA_{DC}

- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing

0 V_{DC} to V^+ -- 1.5 V_{DC}

connection diagrams

Metal Can Package

OUTPUT A OUTPUT 8

INVERTING OUTPUT 8

INVERTING OUTPUT 8

INPUT A OUTPUT 8

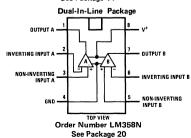
INPUT A OUTPUT 8

INPUT A OUTPUT 8

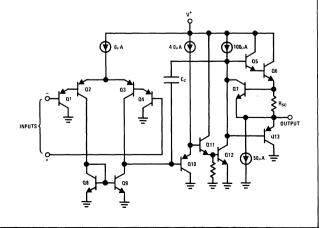
INPUT B OUTPUT B

INPUT B OUTPUT B

Order Number LM158H, LM258H or LM358H See Package 11



schematic diagram (Each Amplifier)



absolute maximum ratings

Supply Voltage, V^{\dagger} Differential Input Voltage Input Voltage

32 V_{DC} or ±16 V_{DC} 32 V_{DC} -0.3 V_{DC} to +32 V_{DC}

Continuous

Operating Temperature Range

Power Dissipation (Note 1) Molded DIP (LM358N) Metal Can

570 mW (LM158H, LM258H & LM358H) 500 mW LM358 LM258 LM158

0°C to +70°C -25°C to +85°C -55°C to +125°C

50 mA

Output Short-Circuit to GND (Note 2) (One Amplifier)

 $V^+ \le 15 \text{ V}_{DC}$ and $T_A = 25^{\circ}\text{C}$

Storage Temperature Range Lead Temperature (Soldering, 10 seconds)

Input Current ($V_{IN} < -0.3 V_{OL}$) (Note 3)

-65°C to +150°C 300°C

electrical characteristics (V⁺ = +5.0 V_{DC}, Note 4) LM158

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	T _A = +25°C (Note 5)		±2	±5	mV _{DC}
Input Bias Current (Note 6)	$I_{IN(+)}$ or $I_{IN(-)}$, $T_A = +25^{\circ}C$		45	150	nA _{DC}
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, T_A = +25^{\circ}C$		±3	±30	nApc
Input Common-Mode Voltage Range (Note 7)	$V^{+} = 30 \text{ V}_{DC}, T_{A} = +25^{\circ}\text{C}$	0		V ⁺ −1.5	V _{DC}
Supply Current	R _L = ∞ On All Op Amps Over Full Temperature Range		0.5	1.2	mA _{DC}
Large Signal Voltage Gain	$V^+ = +15 V_{DC}$ (For Large V_O Swing) $R_L \ge 2 k\Omega$, $T_A = +25^{\circ}C$	50	100		V/mV
Common-Mode Rejection Ratio	DC, T _A = +25°C	70	85		dB
Power Supply Rejection Ratio	DC, T _A = +25°C	65	100		dB
Amplifier-to-Amplifier Coupling (Note 8)	f = 1 kHz to 20 kHz, T _A = +25°C (Input Referred)	-	-120		dB
Output Current Source	V_{IN}^{+} = +1 V_{DC} , V_{IN}^{-} = 0 V_{DC} , V^{+} = 15 V_{DC} , T_{A} = +25°C	20	40		mA _{DC}
Sink	$V_{IN}^- = +1 V_{DC}, V_{IN}^+ = 0 V_{DC},$ $V^+ = 15 V_{DC}, T_A = +25^{\circ}C$	10	20		mA _{DC}
	$V_{IN}^- = +1 V_{DC}, V_{IN}^+ = 0 V_{DC},$ $T_A = +25^{\circ}C, V_O = 200 \text{ mV}_{DC}$	12	50		μA _{DC}
Input Offset Voltage	(Note 5)			±7	mV _{DC}
nput Offset Voltage Drift	$R_S = 0\Omega$		7		μV/°C
nput Offset Current	$I_{IN(+)} - I_{IN(-)}$			±100	nA _{DC}
nput Offset Current Drift			10		pA _{DC} /°C
nput Bias Current	I _{IN(+)} or I _{IN(-)}			300	nA _{DC}
nput Common-Mode Voltage Range (Note 7)	V ⁺ = 30 V _{DC}	0		V*−2	V _{DC}
Large Signal Voltage Gain	$V^* = +15 V_{DC}$ (For Large V_O Swing) $R_L \ge 2 k\Omega$	25			V/mV
Output Voltage Swing					
V _{OH}	$V^+ = +30 V_{DC}, R_L = 2 k\Omega$ $R_L \ge 10 k\Omega$	26 27	28		V _{DC}
VoL	$V^+ = +5 V_{DC}, R_L < 10 k\Omega$		5	20	mV _{DC}
Output Current Source	$V_{IN}^{+} = +1 V_{DC}, V_{IN}^{-} = 0 V_{DC}, V^{+} = 15 V_{DC}$	10	20	1	mA
Sink	$V_{IN}^- = +1 V_{DC}, V_{IN}^+ = 0 V_{DC}, V^+ = 15 V_{DC}$	5	8		mA
Differential Input Voltage (Note 7)				V*	V _{DC}

electrical characteristics (V⁺ = +5.0 V_{DC}, Note 4) LM258, LM358

PARAMETER	CONDITIONS	MIN	TYP	· MAX	UNITS
Input Offset Voltage	T _A = +25°C (Note 5)		±2	±6	mV _{DC}
Input Bias Current (Note 6)	$I_{1N(+)}$ or $I_{1N(-)}$, $T_A = +25^{\circ}C$		45	250	nA _{DC}
nput Offset Current	$I_{IN(+)} - I_{IN(-)}, T_A = +25^{\circ}C$		±5	±50	nA _{DC}
Input Common-Mode Voltage Range (Note 7)	V ⁺ = 30 V _{DC} , T _A = +25°C	0		V ⁺ −1.5	V _{DC}
Supply Current	R _L = ∞ On All Op Amps Over Full Temperature Range		0.5	1.2	mA _{DC}
Large Signal Voltage Gain	V^{+} = +15 V_{DC} (For Large V_{O} Swing) $R_{L} \ge 2 \text{ k}\Omega$, T_{A} = +25°C	25	100		V/mV
Common-Mode Rejection Ratio	. DC, T _A = +25"C	70	70		dB
Power Supply Rejection Ratio	DC, T _A = +25 ¹ C	65	100		dB
Amplifier-to-Amplifier Coupling (Note 8)	f = 1 kHz to 20 kHz, T _A = +25°C (Input Referred)	ļ	-120		dB
Output Current Source	$V_{IN}^{+} = +1 V_{DC}, V_{IN}^{-} = 0 V_{DC},$ $V^{+} = 15 V_{DC}, T_{A} = +25^{\circ}C$	20	40		mA _{DC}
Sink	$V_{IN}^{"} = +1 V_{DC}, V_{IN}^{'} = 0 V_{DC},$ $V^{\dagger} = 15 V_{DC}, T_{A} = +25 ^{\circ}C$	10	20		mA _{DC}
	$V_{IN}^{-} = +1 V_{DC}, V_{IN}' = 0 V_{DC},$ $T_A = +25^{\circ}C, V_O = 200 \text{ mV}_{DC}$	12	50		μA _{DC}
Input Offset Voltage	(Note 5)			±7.5	mV _{DC}
nput Offset Voltage Drift	R _S = 0Ω	Ì	7		μV/°C
nput Offset Current	$I_{1N(+)} - I_{1N(-)}$		İ	±150	nA _{DC}
nput Offset Current Drift			10		pA _{DC} /°C
nput Bias Current	I _{IN(+)} or I _{IN(-)}			500	nA _{DC}
Input Common-Mode Voltage Range (Note 7)	V* = 30 V _{DC}	0		V*-2	V _{DC}
Large Signal Voltage Gain	V^* = +15 V_{DC} (For Large V_O Swing) $R_L \ge 2 k\Omega$	15			V/mV
Output Voltage Swing V _{OH}	$V^* = +30 \text{ V}_{\text{DC}}, \text{ R}_{\text{L}} = 2 \text{ k}\Omega$ $\text{R}_{\text{L}} \ge 10 \text{ k}\Omega$	26 27	28		V _{DC}
VoL	$V^{+} = +5 V_{DC}, R_{L} < 10 k\Omega$	1	5	20	mV _{DC}
Output Current Source	V_{IN}^{+} = +1 V_{DC} , V_{IN}^{-} = 0 V_{DC} , V^{+} = 15 V_{DC}	10	20		mA
Sink	$V_{IN}^- = +1 V_{DC}, V_{IN}^+ = 0 V_{DC}, V^+ = 15 V_{DC}$	5	8		mA
Differential Input Voltage (Note 7)				V*	V _{DC}

Note 1: For operating at high temperatures, the LM358 must be derated based on a +125°C maximum junction temperature and a thermal resistance of 175°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM258 and LM158 can be derated based on a +150°C maximum junction temperature. The dissipation is the total of both amplifiers—use external resistors, where possible, to allow the amplifier to saturate or to reduce the power which is dissipated in the integrated circuit.

Note 2: Short circuits from the output to V⁺ can cause excessive heating and eventual destruction. The maximum output current is approximately 40 mA independent of the magnitude of V⁺. At values of supply voltage in excess of +15 V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.

Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V⁺ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V_{DC}.

Note 4: These specifications apply for V⁺ = +5 V_{DC} and -55°C \leq T_A \leq +125°C, unless otherwise stated. With the LM258, all temperature specifications are limited to -25°C \leq T_A \leq +85°C and the LM358 temperature specifications are limited to 0°C \leq T_A \leq +70°C.

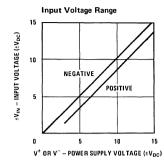
Note 5: $V_O \cong 1.4 \ V_{DC}$, $R_S = 0 \Omega$ with V^+ from 5 V_{DC} to 30 V_{DC} ; and over the full input common-mode range (0 V_{DC} to $V^+ - 1.5 \ V_{DC}$).

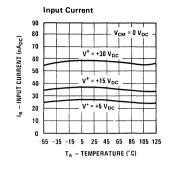
Note 6: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

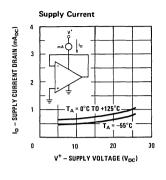
Note 7: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V^+ - 1.5V$, but either or both inputs can go to $+32~V_{DC}$ without damage.

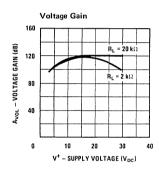
Note 8: Due to proximity of external components, insure that coupling is not originating via the stray capacitance between these external parts. This typically can be detected as this type of capacitive coupling increases at higher frequencies.

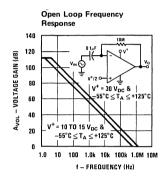
typical performance characteristics

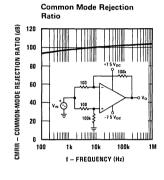


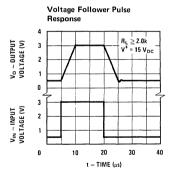


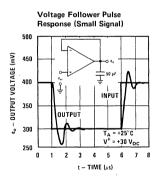


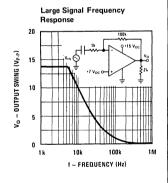


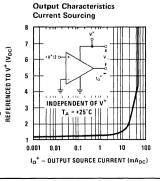




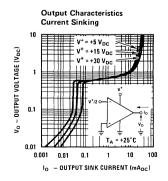


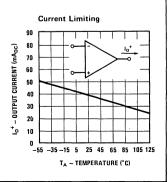






- OUTPUT VOLTAGE





application hints

The LM158 series are op amps which operate with only a single power supply voltage, have true-differential inputs, and remain in the linear mode with an input common-mode voltage of 0 $V_{\rm DC}.$ These amplifiers operate over a wide range of power supply voltages with little change in performance characteristics. At $25^{\circ}{\rm C}$ amplifier operation is possible down to a minimum supply voltage of 2.3 $V_{\rm DC}.$

Precautions should be taken to insure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a test socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V⁺ without damaging the device. Protection should be provided to prevent the input voltages from going negative more than $-0.3 \, V_{DC}$ (at 25° C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply current drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For ac applications, where the load is capacitively coupled to the output of the amplifier, a resistor should be used, from the output of the amplifier to ground to increase the class A bias current and prevent crossover

distortion. Where the load is directly coupled, as in dc applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50 pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

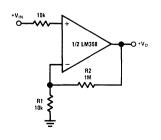
The bias network of the LM158 establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from 3 $V_{\rm DC}$ to 30 $V_{\rm DC}$.

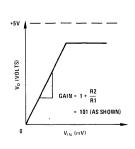
Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive junction temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at 25°C provides a larger output current capability at elevated temperatures (see typical performance characteristics) than a standard IC op amp.

The circuits presented in the section on typical applications emphasize operation on only a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of $V^+/2$) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.

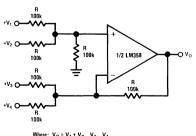
typical single-supply applications ($V^+ = 5.0 V_{DC}$)

Non-Inverting DC Gain (0V Input = 0V Output)





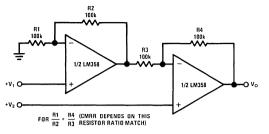
DC Summing Amplifier (V_{IN'S} \geq 0 V_{DC} AND V_O \geq 0 V_{DC})



Where: $V_0 = V_1 + V_2 - V_3 - V_4$ $(V_1 + V_2) \ge (V_3 + V_4)$ to keep $V_0 \ge 0$ V_{DC}

typical single-supply applications (con't) ($V^+ = 5.0 V_{DC}$)

High Input Z, DC Differential Amplifier



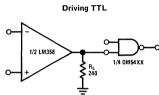
 $V_0 = \left(1 + \frac{R4}{R3}\right) (V_2 - V_1)$

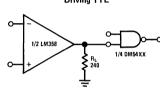
AS SHOWN: Vo = 2(V2 - V1)

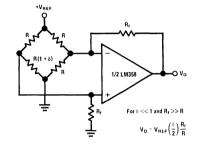
ICELL 1/2 LM358 (CELL HAS OV ACROSS IT)

Photo Voltaic-Cell Amplifier

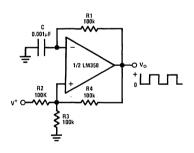
Bridge Current Amplifier

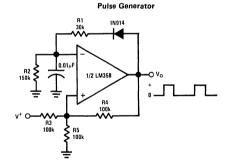




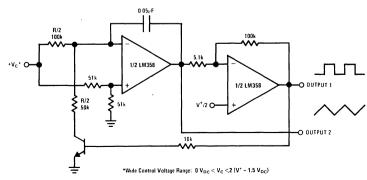






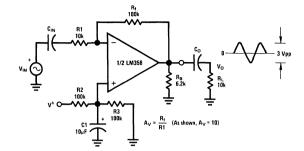


Voltage Controlled Oscillator (VCO)

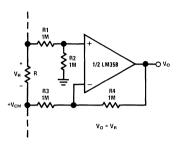


typical single-supply applications (con't) $(V^+ = 5.0 V_{DC})$

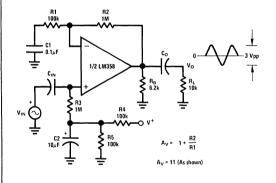
AC Coupled Inverting Amplifier



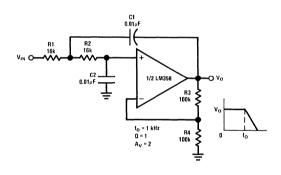
Ground Referencing A Differential Input Signal



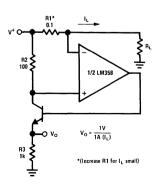
AC Coupled Non-Inverting Amplifier



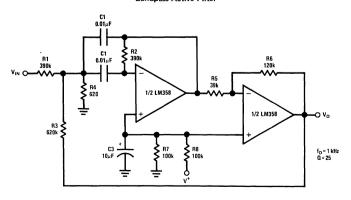
DC Coupled Low-Pass RC Active Filter



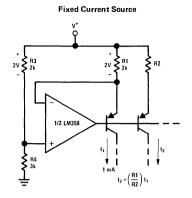


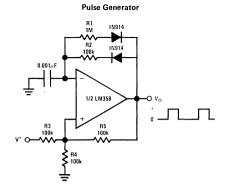


Bandpass Active Filter



typical single-supply applications (con't) ($V^+ = 5.0 V_{DC}$)





Lamp Driver

